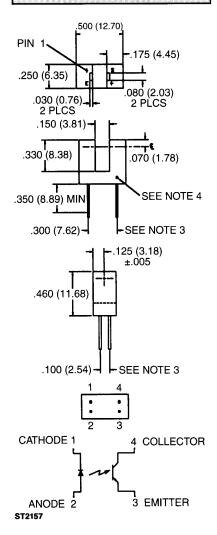


SLOTTED OPTICAL SWITCH

OPB804

PACKAGE DIMENSIONS



NOTES:

- 1. DIMENSIONS ARE IN INCHES (mm.)
- 2. TOLERANCE IS ±.010 (0.25)
 UNLESS OTHERWISE SPECIFIED.
- 3. THIS DIMENSION IS CONTROLLED AT THE HOUSING SURFACE.
- WHITE DOT ADJACENT TO COLLECTOR LEAD.

DESCRIPTION

The OPB804 is an optical slotted switch that consists of an infrared emitting diode facing and NPN phototransistor across a .150" (3.81 mm) gap. Phototransistor switching takes place when an opaque object breaks the light path.

FEATURES

- .150" wide gap.
- .300" lead spacing.
- Printed circuit board mounting.
- Non contact switching.
- 2mm aperture width.



SLOTTED OPTICAL SWITCH

Storage Temperature Operating Temperature	40°C to + 85°C 40°C to + 85°C
Soldering: Lead Temperature (Iron) Lead Temperature (Flow)	
INPUT DIODE Continuous Forward Current Reverse Voltage Power Dissipation	
OUTPUT TRANSISTOR Collector-Emitter Voltage Emitter-Collector Voltage Power Dissipation	5.0 Vol

PARAMETER	SYMBOL	MIN.	TYPE.	MAX.	UNITS	TEST CONDITIONS
INPUT DIODE						
Forward voltage	$V_{\scriptscriptstyle F}$	_		1.70	V	$I_F = 20 \text{ mA}$
Reverse Leakage Current	l _e	_		100	. μΑ	$V_{R} = 5.0 \text{ V}$
OUTPUT TRANSISTOR						
Collector-Emitter Breakdown	BV_{ECO}	30		_	V	$I_c = 100 \ \mu\text{A}, Ee = 0$
Collector-Emitter Breakdown	BV _{CEO}	5		_	٧	$I_{\varepsilon} = 100 \ \mu A, Ee = 0$
Collector-Emitter Leakage	I _{CEO}	_		100	nA	$V_{CE} = 10.0 \text{ V}, Ee = 0$
COUPLED						
On-State Collector Current						
OPB706A	I _{C(ON)}	500		_	μΑ	$I_{\scriptscriptstyle F}=20$ mA, $V_{\scriptscriptstyle CC}=5.0$ V, $D=.050''$ $^{\scriptscriptstyle (5,7)}$
OPB706B	I _{C(ON)}	350			μΑ	$I_{\rm F} = 20$ mA, $V_{\rm CC} = 5.0$ V, $D = .050''$ (5.7)
OPB706C	I _{C(ON)}	200		_	μΑ	$I_{\rm F} = 20$ mA, $V_{\rm CC} = 5.0$ V, D = $.050''$ (5.7)
Crosstalk	I _{cx}	_	200	_	nA	$I_F = 20 \text{ mA}, V_{CC} = 5.0 \text{ V}, \text{ Ee} = 0^{(6)}$
Saturation Voltage	V _{CE(SAT)}			0.40	٧	$I_F = 40 \text{ mA}, I_C = 100 \mu\text{A}, D = .050''^{(5.7)}$

NOTES

- 1. Derate power dissipation linearly 1.25 mW/°C above 25°C.
- 2. RMA flux is recommended.

- As long as leads are not under any stress or spring tension.
 D is the distance from the sensor face to the reflective surface.
 Crosstalk (I_{cx}) is the collector current measured with the indicated current on the input diode and with no reflective surface.
 Measured using Eastman Kodak neutral white test card with 90% diffused reflectance as a reflecting surface.



SLOTTED OPTICAL SWITCH

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